

# Polar™ Power MOSFETs

## IXTY1R4N100P IXTA1R4N100P IXTP1R4N100P

$$V_{DSS} = 1000V$$

$$I_{D25} = 1.4A$$

$$R_{DS(on)} \leq 11.8\Omega$$

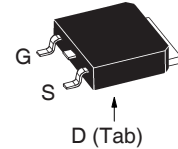
N-Channel Enhancement Mode  
Avalanche Rated



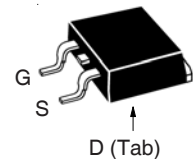
| Symbol        | Test Conditions  | Maximum Ratings  |            |
|---------------|--|------------------|------------|
| $V_{DSS}$     | $T_J = 25^\circ C$ to $150^\circ C$                                | 1000             | V          |
| $V_{DGR}$     | $T_J = 25^\circ C$ to $150^\circ C$ , $R_{GS} = 1M\Omega$          | 1000             | V          |
| $V_{GSS}$     | Continuous   | $\pm 20$         | V          |
| $V_{GSM}$     | Transient  | $\pm 30$         | V          |
| $I_{D25}$     | $T_C = 25^\circ C$   | 1.4              | A          |
| $I_{DM}$      | $T_C = 25^\circ C$ , Pulse Width Limited by $T_{JM}$               | 3.0              | A          |
| $I_A$         | $T_C = 25^\circ C$   | 1.4              | A          |
| $E_{AS}$      | $T_C = 25^\circ C$   | 100              | mJ         |
| $dv/dt$       | $I_S \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ C$ | 10               | V/ns       |
| $P_D$         | $T_C = 25^\circ C$   | 63               | W          |
| $T_J$         |  | -55 ... +150     | $^\circ C$ |
| $T_{JM}$      |  | 150              | $^\circ C$ |
| $T_{stg}$     |  | -55 ... +150     | $^\circ C$ |
| $T_L$         | 1.6mm (0.062) from Case for 10s                                    | 300              | $^\circ C$ |
| $T_{SOLD}$    | Plastic Body for 10s   | 260              | $^\circ C$ |
| $F_C$         | Mounting Force (TO-263)  | 10..65/2.2..14.6 | N/lb.      |
| $M_d$         | Mounting Torque (TO-220)   | 1.13 / 10        | Nm/lb.in.  |
| <b>Weight</b> | TO-252   | 0.35             | g          |
|               | TO-263   | 2.50             | g          |
|               | TO-220   | 3.00             | g          |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ C$ , Unless Otherwise Specified) | Characteristic Values |      |               |
|--------------|---|-----------------------|------|---------------|
|              |   | Min.                  | Typ. | Max.          |
| $BV_{DSS}$   | $V_{GS} = 0V$ , $I_D = 250\mu A$                                      | 1000                  |      | V             |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 50\mu A$                                   | 2.5                   |      | 4.5 V         |
| $I_{GSS}$    | $V_{GS} = \pm 20V$ , $V_{DS} = 0V$                                    |                       |      | $\pm 50$ nA   |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$ , $V_{GS} = 0V$<br>$T_J = 125^\circ C$             |                       |      | 5 $\mu A$     |
|              |   |                       |      | 150 $\mu A$   |
| $R_{DS(on)}$ | $V_{GS} = 10V$ , $I_D = 0.5 \cdot I_{D25}$ , Note 1                   |                       |      | 11.8 $\Omega$ |

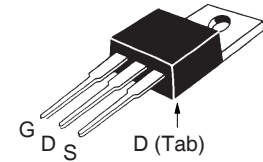
### TO-252 (IXTY)



### TO-263 AA (IXTA)



### TO-220AB (IXTP)



G = Gate      D = Drain  
S = Source    Tab = Drain

### Features

- International Standard Packages
- Low  $R_{DS(on)}$  and  $Q_G$
- Avalanche Rated
- Low Package Inductance
- Fast Intrinsic Rectifier

### Advantages

- High Power Density
- Easy to Mount
- Space Savings

### Applications

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls

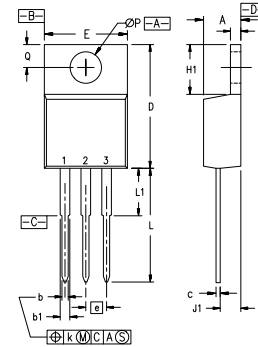
| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)   | Characteristic Values |      |                       |
|--------------|---|-----------------------|------|-----------------------|
|              |   | Min.                  | Typ. | Max                   |
| $g_{fs}$     | $V_{DS} = 20\text{V}$ , $I_D = 0.5 \cdot I_{D25}$ , Note 1  | 0.70                  | 1.10 | S                     |
| $C_{iss}$    | $V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$  |                       | 450  | pF                    |
| $C_{oss}$    |   |                       | 27   | pF                    |
| $C_{rss}$    |   |                       | 6    | pF                    |
| $t_{d(on)}$  | <b>Resistive Switching Times</b><br>$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$<br>$R_G = 30\Omega$ (External) |                       | 25   | ns                    |
| $t_r$        |   |                       | 35   | ns                    |
| $t_{d(off)}$ |   |                       | 65   | ns                    |
| $t_f$        |   |                       | 28   | ns                    |
| $Q_{g(on)}$  | $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$  |                       | 17.8 | nC                    |
| $Q_{gs}$     |   |                       | 2.8  | nC                    |
| $Q_{gd}$     |   |                       | 9.9  | nC                    |
| $R_{thJC}$   | TO-220  |                       | 0.50 | $2.0^\circ\text{C/W}$ |
| $R_{thCS}$   |   |                       |      | $^\circ\text{C/W}$    |

**Source-Drain Diode**

| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                              | Characteristic Values |      |       |
|----------|--|-----------------------|------|-------|
|          |  | Min.                  | Typ. | Max   |
| $I_s$    | $V_{GS} = 0\text{V}$   |                       |      | 1.4 A |
| $I_{SM}$ | Repetitive, Pulse Width Limited by $T_{JM}$  |                       |      | 4.2 A |
| $V_{SD}$ | $I_F = I_s$ , $V_{GS} = 0\text{V}$ , Note 1  |                       |      | 1.5 V |
| $t_{rr}$ | $I_F = 1.4\text{A}$ , $-di/dt = 100\text{A}/\mu\text{s}$ ,<br>$V_R = 100\text{V}$ , $V_{GS} = 0\text{V}$ |                       | 750  | ns    |

Note 1: Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

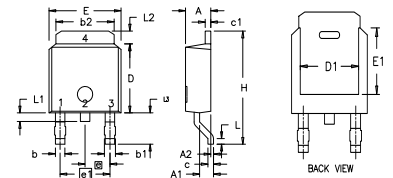
**TO-220 (IXTP) Outline**



Pins: 1 - Gate 2 - Drain  
3 - Source

| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .170     | .190 | 4.32        | 4.83  |
| b   | .025     | .040 | 0.64        | 1.02  |
| b1  | .045     | .065 | 1.15        | 1.65  |
| c   | .014     | .022 | 0.35        | 0.56  |
| D   | .580     | .630 | 14.73       | 16.00 |
| E   | .390     | .420 | 9.91        | 10.66 |
| e   | .100 BSC |      | 2.54 BSC    |       |
| F   | .045     | .055 | 1.14        | 1.40  |
| H1  | .230     | .270 | 5.85        | 6.85  |
| J1  | .090     | .110 | 2.29        | 2.79  |
| k   | 0        | .015 | 0           | 0.38  |
| L   | .500     | .550 | 12.70       | 13.97 |
| L1  | .110     | .230 | 2.79        | 5.84  |
| ØP  | .139     | .161 | 3.53        | 4.08  |
| Q   | .100     | .125 | 2.54        | 3.18  |

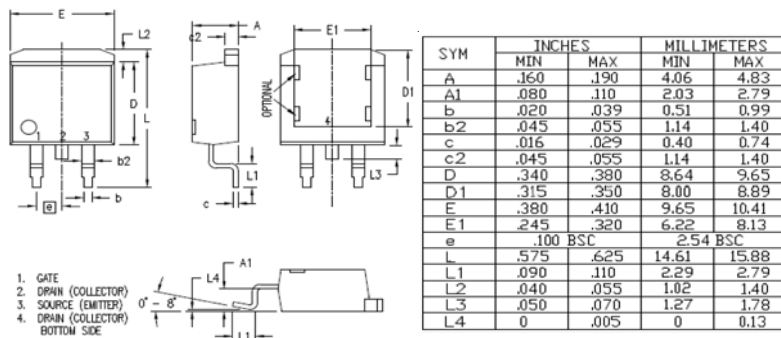
**TO-252 (IXTY) Outline**



Pins: 1 - Gate 2,4 - Drain  
3 - Source

| Dim. | Millimeter |       | Inches    |       |
|------|------------|-------|-----------|-------|
|      | Min.       | Max.  | Min.      | Max.  |
| A    | 2.19       | 2.38  | 0.086     | 0.094 |
| A1   | 0.89       | 1.14  | 0.035     | 0.045 |
| A2   | 0          | 0.13  | 0         | 0.005 |
| b    | 0.64       | 0.89  | 0.025     | 0.035 |
| b1   | 0.76       | 1.14  | 0.030     | 0.045 |
| b2   | 5.21       | 5.46  | 0.205     | 0.215 |
| c    | 0.46       | 0.58  | 0.018     | 0.023 |
| c1   | 0.46       | 0.58  | 0.018     | 0.023 |
| D    | 5.97       | 6.22  | 0.235     | 0.245 |
| D1   | 4.32       | 5.21  | 0.170     | 0.205 |
| E    | 6.35       | 6.73  | 0.250     | 0.265 |
| E1   | 4.32       | 5.21  | 0.170     | 0.205 |
| e    | 2.28 BSC   |       | 0.090 BSC |       |
| e1   | 4.57 BSC   |       | 0.180 BSC |       |
| H    | 9.40       | 10.42 | 0.370     | 0.410 |
| L    | 0.51       | 1.02  | 0.020     | 0.040 |
| L1   | 0.64       | 1.02  | 0.025     | 0.040 |
| L2   | 0.89       | 1.27  | 0.035     | 0.050 |
| L3   | 2.54       | 2.92  | 0.100     | 0.115 |

**TO-263 (IXTA) Outline**



| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .160     | .190 | 4.06        | 4.83  |
| A1  | .080     | .110 | 2.03        | 2.79  |
| b   | .020     | .039 | 0.51        | 0.99  |
| b2  | .045     | .055 | 1.14        | 1.40  |
| c   | .016     | .029 | 0.40        | 0.74  |
| c2  | .045     | .055 | 1.14        | 1.40  |
| D   | .340     | .380 | 8.64        | 9.65  |
| D1  | .315     | .350 | 8.00        | 8.89  |
| E   | .380     | .410 | 9.65        | 10.41 |
| E1  | .245     | .320 | 6.22        | 8.13  |
| e   | .100 BSC |      | 2.54 BSC    |       |
| L   | .575     | .625 | 14.61       | 15.88 |
| L1  | .090     | .110 | 2.29        | 2.79  |
| L2  | .040     | .055 | 1.02        | 1.40  |
| L3  | .050     | .070 | 1.27        | 1.78  |
| L4  | 0        | .005 | 0           | 0.13  |

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

|  |           |           |           |           |              |              |              |              |              |             |
|--|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
|  | 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
|  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$

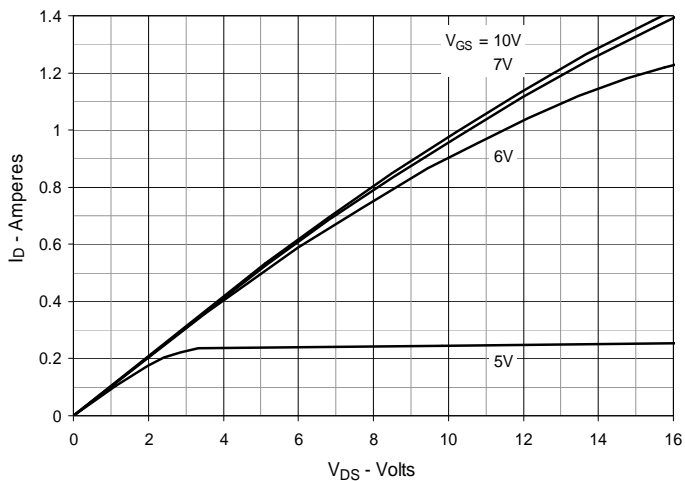


Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$

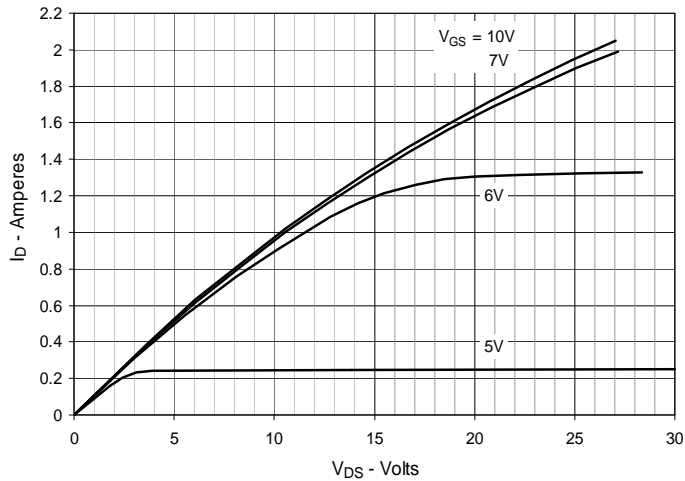


Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$

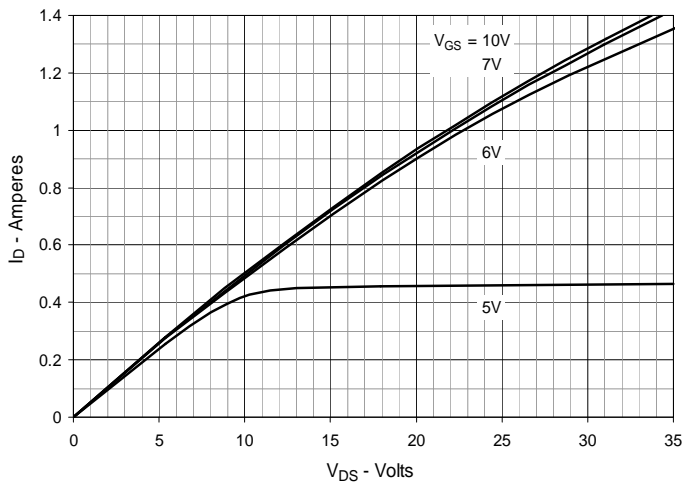


Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 0.7\text{A}$  Value vs. Junction Temperature

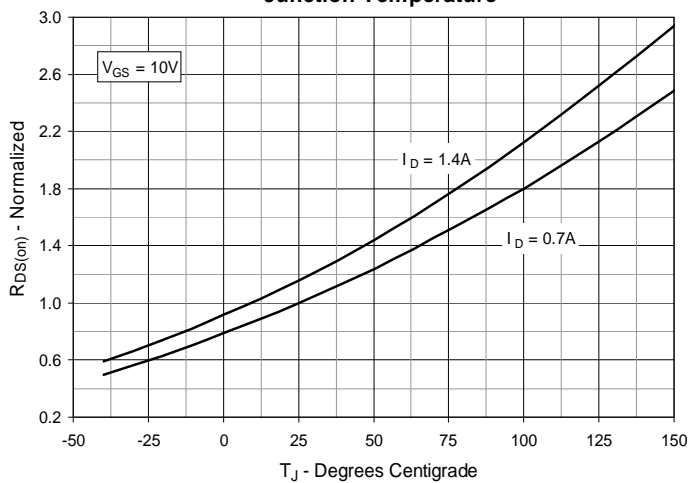


Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 0.7\text{A}$  Value vs. Drain Current

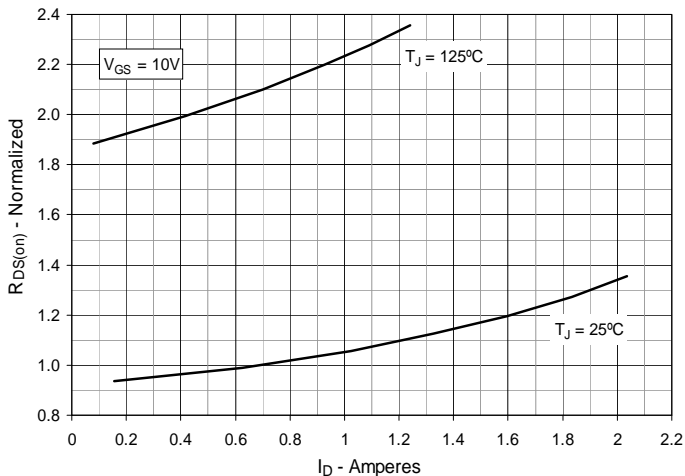
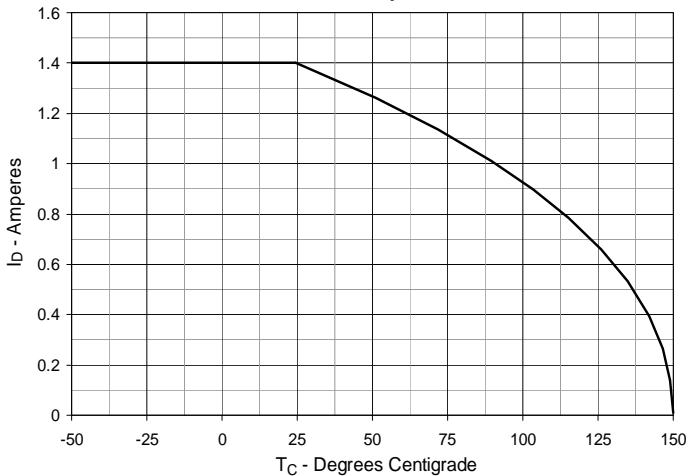
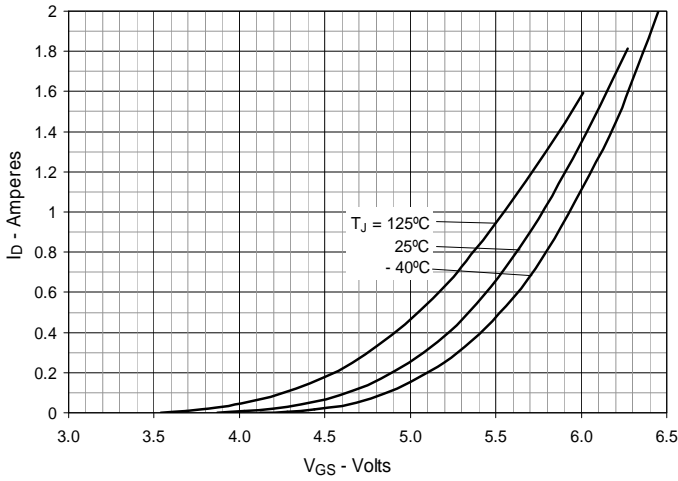


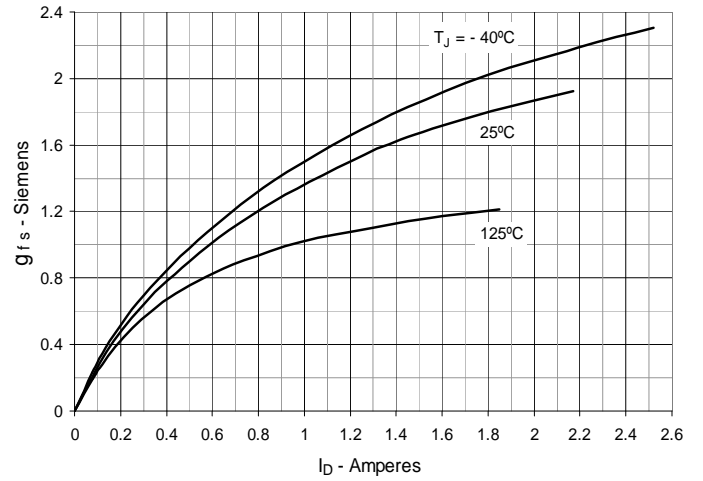
Fig. 6. Maximum Drain Current vs. Case Temperature



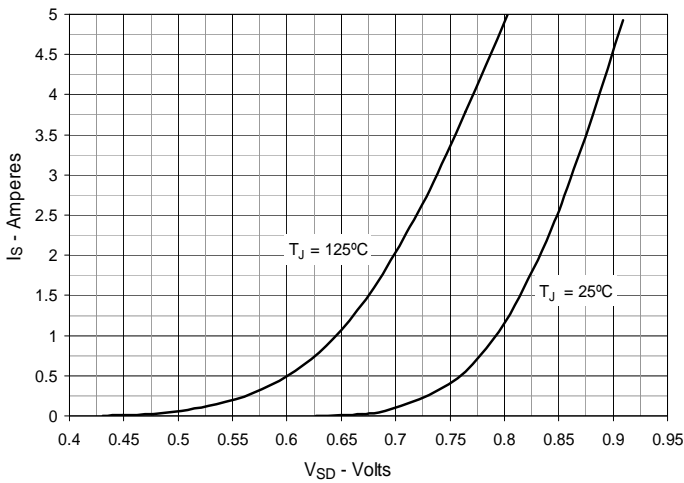
**Fig. 7. Input Admittance**



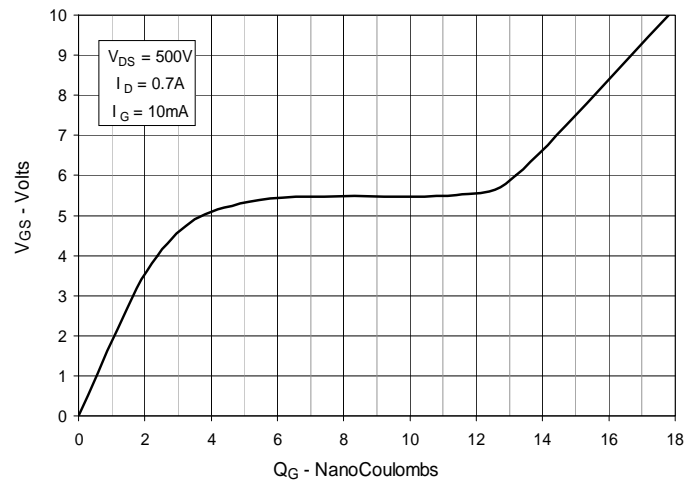
**Fig. 8. Transconductance**



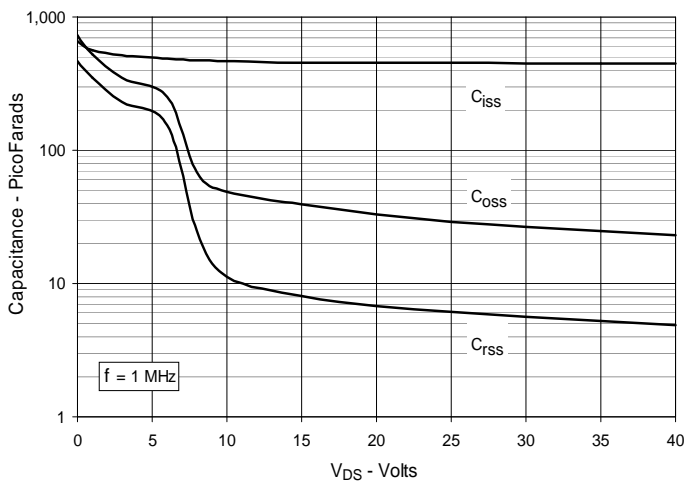
**Fig. 9. Forward Voltage Drop of Intrinsic Diode**



**Fig. 10. Gate Charge**



**Fig. 11. Capacitance**



**Fig. 12. Maximum Transient Thermal Impedance**

